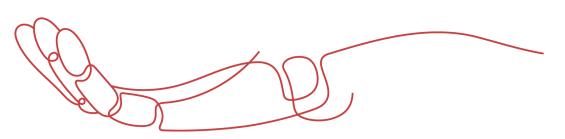




PRODUCT DATA SHEET



To learn more about JGSEMI, please visit our website at







Datasheet

urces Samples

Please note: Please check the JINGAO Semiconductor website to verify the updated device numbers. The most current and up-to-date ordering information can be found at www.jg-semi.cn. Please email any questions regarding the system integration to JINGAO_questions@jgsemi.com.



NPN Transistors

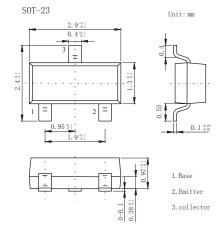
Features

Low noise and high gain.

NF = 1.1 dB Typ., Ga = 11 dB Typ. @VCE = 10 V, IC = 7 mA, f = 1.0 GHz

• High power gain.

MAG = 13 dB Typ. @VcE = 10 V, Ic = 20 mA, f = 1.0 GHz



■ Absolute Maximum Ratings Ta = 25 °C

Parameter	Symbol	Rating	Unit	
Collector to base voltage	Vсво	20	V	
Collector to emitter voltage	VCEO	12	V	
Emitter to base voltage	Vево	3.0	V	
Collector current (DC)	Ic	100	mA	
Total power dissipation	Ptot	200	mW	
Junction temperature	Tj	150	$^{\circ}$	
Storage temperature range	Tstg	-65 to +150	$^{\circ}\!\mathbb{C}$	

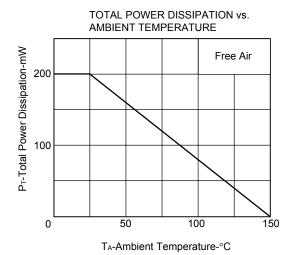
■ Electrical Characteristics Ta = 25°C

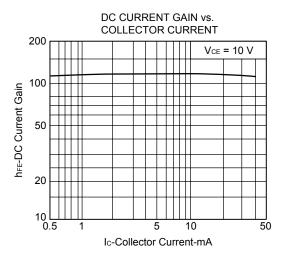
Parameter	Symbol	Test Conditions	Min	Тур	Max	Unit
Collector- base breakdown voltage	Vсво	Ic= 100 μA, IE= 0	20			
Collector- emitter breakdown voltage	VCEO	Ic= 1 mA, I _B = 0	12			V
Emitter - base breakdown voltage	VEBO	IE= 100 uA, IC= 0	3			
Collector-base cut-off current	Ісво	Vcb= 10 V , IE= 0			1	uA
Emitter cut-off current	ІЕВО	VEB= 3V , IC=0			1	
Collector-emitter saturation voltage *	VCE(sat)	Ic=50 mA, I _B =5mA			0.4	V
Base - emitter saturation voltage *	VBE(sat)	Ic=50 mA, I _B =5mA			1.2	
DC current gain *	hfe	VcE= 10V, Ic= 20mA	50		400	
Insertion power gain	S21e ²	VcE = 10 V, Ic = 20 mA, f= 1GHz		11.5		dB
Noise figure	NF	VcE = 10 V, Ic = 7 mA, f= 1GHz		1.1	2	
Reverse transfer capacitance	Cre	Vcb= 10V, IE= 0,f=1MHz		0.55	1	pF
Transition frequency	fτ	VcE= 10V, Ic= 20mA		7		GHz

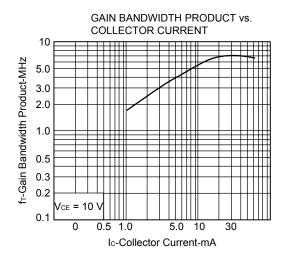
^{*.} Pulse measurement: PW \leqslant 350 $\,\mu$ s, Duty Cycle \leqslant 2%.

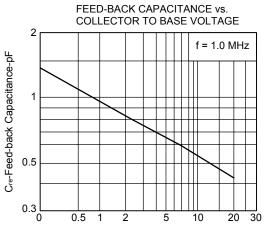


■ Typical Characterisitics

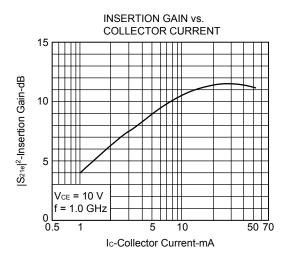


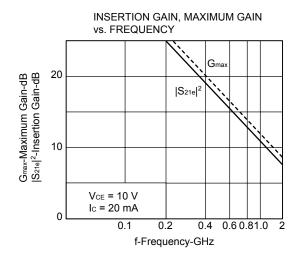






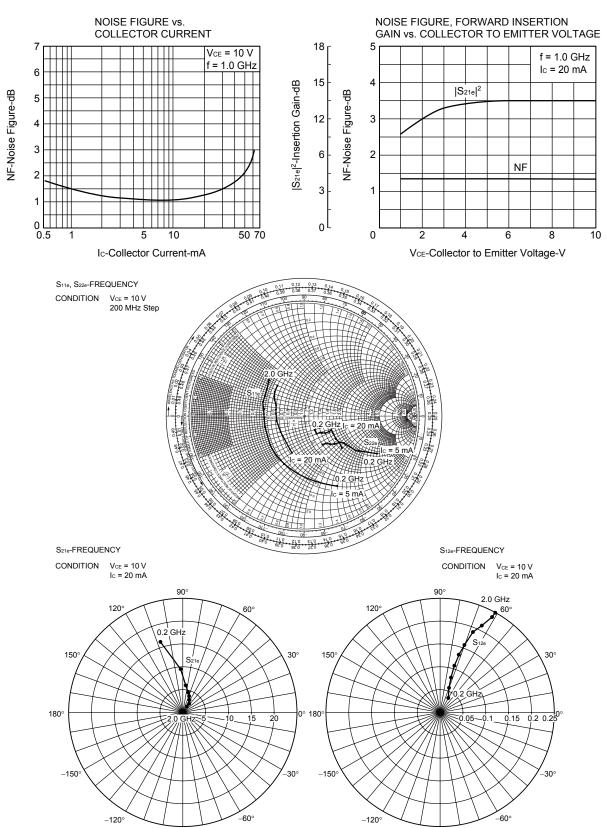
VcB-Collector to Base Voltage-V







■ Typical Characterisitics



-90°

–90°



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